NSN 5962-01-535-6032

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5962-01-535-6032

Body Length: 0.960 inches

Body Width:

Between 0.220 inches and 0.310 inches

Body Height:

Between 0.130 inches and 0.185 inches

Maximum Power Dissipation Rating:

950.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Plus 4 dgu

Features Provided:

Electrostatic sensitive and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute

Product Name:

Microcircuit assembly sin-low

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source and -1.5 volts input and 5.5 volts input

Time Rating Per Chacteristic:

90.00 nanoseconds access

Memory Device Type:

Prom

Memory Capacity:

2k x 4

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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Fiig: A458a0

